

CONTENTS

<i>List of Figures</i>	<i>xix-xxii</i>
<i>List of Tables</i>	<i>xxiii-xxiv</i>
<i>List of Abbreviations</i>	<i>xxv-xxvi</i>
<i>List of Symbols</i>	<i>xxvii-xxx</i>
<i>Abstract</i>	<i>xxxi-xxxiv</i>

Chapter 1 **01-20**

Introduction and Scope of the Thesis

1.1	Introduction	01
1.1.1	Early 20 th Century Research	01
1.1.2	The Years 1920-1940	02
1.1.3	The Years 1940-1950	03
1.1.4	The Years 1950-1960	03
1.1.5	The Years 1960-1970	04
1.1.6	The Years 1970-1980	04
1.1.7	The Years 1980 and beyond	05
1.2	Terahertz Spectral Region	08
1.3	Properties of THz Radiation	09
1.3.1	Non-Ionizing	10
1.3.2	Penetration	10
1.3.3	Safety	10
1.3.4	Resolution	11
1.3.5	Scattering	11
1.3.6	Atmospheric Transmission	12
1.4	Applications of THz Region	13
1.4.1	Astronomy	13
1.4.2	Packaging and Quality Control	13
1.4.3	Security	14
1.4.4	Medical Applications	15
1.4.5	Art and Archaeology	16
1.4.6	Material Characterization	16
1.4.7	Wireless Communication	16

1.5	Outline of the Thesis	17
Chapter 2		21-42
Review of Terahertz Detectors		
2.1	Introduction	21
2.2	A Few Current Detector Technologies	22
2.2.1	Bolometers	22
2.2.2	Microbolometers	23
2.2.3	Pyroelectric Detectors	24
2.2.4	Golay Cells	24
2.2.5	Schottky Barrier Diode	25
2.2.6	Graphene Detectors	26
2.3	State-of-the-art THz Detectors	28
2.3.1	Mercury Cadmium Telluride	28
2.3.2	Material Properties of MCT	29
2.3.2.1	Crystal Structure	30
2.3.2.2	Band Structure	31
2.3.2.3	Optical Properties	37
2.4	Need for Cooling	40
2.5	Motivation	41
Chapter 3		43-74
A Single Heterojunction n-i-p Photodetector Based on Mercury Cadmium Telluride for Terahertz Applications		
3.1	Introduction	43
3.2	Proposed Device Structure	44
3.3	Numerical Simulation	46
3.3.1	Poisson's equation	46
3.3.2	Continuity equations	47
3.3.3	Transport equations	50
3.4	Material Properties	53
3.5	Modeling of Carrier Lifetime	54
3.5.1	Radiative Mechanism	54
3.5.2	Shockley Read-Hall Mechanism	55

3.5.3	Auger Mechanism	56
3.6	Dark Current Modeling	58
3.6.1	Diffusion Currents	60
3.6.2	Generation-Recombination Currents	61
3.6.3	Tunneling Currents	61
3.6.4	Quantum Efficiency Modeling	62
3.6.5	Modeling of Specific Detectivity	63
3.6.6	Modeling of Current Responsivity	63
3.6.7	Noise Equivalent Power	64
3.7	Results and Discussion	64
3.8	Conclusion	73
 Chapter 4		75-92
 A Double Heterojunction n-i-p Photodetector Based on Mercury Cadmium Telluride for Terahertz Applications		
4.1	Introduction	75
4.2	Device Structure and Material Parameters	76
4.3	Simulation Methodology	78
4.4	Analytical Modeling	80
4.4.1	Dark Current Modeling	80
4.4.2	Optical Characterization	81
4.5	Results and Discussion	82
4.6	Conclusion	92
 Chapter 5		93-106
 A Schottky Diode Detector for the Terahertz Regime		
5.1	Introduction	93
5.2	Structure Description	94
5.3	Numerical Simulation	96
5.4	Results and Discussion	97
5.5	Conclusion	106

Chapter 6	107-124
A Proposed Graphene-Gated Semiconductor Terahertz Detector	
6.1 Introduction	107
6.2 Structure Description	108
6.3 Analytical Modeling	109
6.3.1 Induced Photovoltage	113
6.3.2 Current-Voltage Characteristics	115
6.4 Results and Discussion	117
6.5 Conclusion	124
Chapter 7	125-130
Conclusion and Future Scope	
7.1 Major Contributions	125
7.2 Future Scope	129
<i>References</i>	131-156
<i>List of Publications</i>	157